



SYLLABUS

1. Data about the program of study

Technical University of Cluj-Napoca
Faculty of Electronics, Telecommunications and information
Technology
Applied Electronics
Electronic Engineering, Telecommunications and Information
Technologies
Bachelor of Science
Applied Electronics / Engineer
Full time
18.00

2. Data about the subject

2.1 Subject name		Mate	erials	for E	lectronics			
		Theoretical area Methodological area						
-			ytic a	•				
2.3 Course responsible	е		Lect. Prof. Alexandra Fodor, PhD Eng. Alexandra.Fodor@ael.utclu			utcluj.ro		
2.4 Teacher in charge / laboratory / project	witł	n seminar	minar Lect. Prof. Ionuţ Ciocan, PhD Eng. Ionut.Ciocan@ael.utcluj.ro					
2.5 Year of study	11	2.6 Semes	ster	1	2.7 Assessment	Ε	2.8 Subject category	DID/DI

3. Estimated total time

3.1 Number of hours per week	3	of which:	3.2 course	2	3.3 seminar / laboratory	1
3.4 To Total hours in the curriculum	100	of which:	3.5 course	28	3.6 seminar / laboratory	14
Distribution of time						hours
Manual, lecture material and notes, b	ibliogr	aphy				24
Supplementary study in the library, online specialized platforms and in the field					12	
Preparation for seminars / laboratories, homework, reports, portfolios and essays					14	
Tutoring					5	
Exams and tests					3	
Other activities:						
3.7 Total hours of individual study 58						

3.8 Total hours per semester	100
3.9 Number of credit points	4

4. Pre-requisites (where appropriate)

4.1 curriculum	-
4.2 competence	Relations and theorems for electric circuits; physics; chemistry;

5. Requirements (where appropriate)

5.1. for the course	Amphitheatre, Cluj-Napoca
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or the seminars / laboratories / projects Laboratory, Cluj-Napoca
cific competences
 C1 - To use the fundamental elements regarding electronic devices, circuits, systems, instrumentation and technology C1.4 Use of electronic tools and specific methods to characterize and evaluate the performance of electronic circuits and systems C1.5 Providing a theoretical background for the characteristics of the designed systems C4 - To design and use low complexity hardware and software applications, specific to applied electronics C4.3 Identification and optimization of hardware and software solutions of problems related to: industrial electronics, medical electronics, automotive electronics, automation, robotics, production of consumer goods C4.4 Use of appropriate performance criteria for the evaluation, including by simulation, of hardware and software of dedicated systems or service activities in which microcontrollers or computing systems of reduced or medium complexity are used C5 - To apply knowledge, concepts and basic methods from power electronics, automated systems, electric energy management, electromagnetic compatibility C5.2 Qualitative and quantitative interpretation of the functioning of circuits in the fields of: power electronics, automatic systems, electricity management, medical electronics, auto electronics, automatic systems, electricity management in the fields of applied electronics: power electronics, automatic systems, electricity management in the fields of applied electronics automatic systems, electricity management, medical electronics, automatic systems, electricity management, testing and troubleshooting of the applied and environment in the fields of applied electronics

7. Discipline objectives (as results from the key competences gained)

7.1 General objective	Development of competences in the field of materials used in electronics.
7.2 Specific objectives	 Assimilation of theoretical knowledge regarding the materials used in electronics. Acquiring skills for the use of laboratory equipment.

8. Contents



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Facultatea de Electronică, Telecomunicații și Tehnologia Informației

	cture (syllabus)	Teaching methods	Notes
	Course description. An overview of electronic materials.		
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3.			00
4.		, prob study,	ckt
	semiconductors	e s	bla
5.	Dielectric materials – definitions, classifications and general	case	Ľ,
	aspects	ů itic	ecto
	Fundamental properties of dielectrics	n pl cise	ΞŌ
	Applications of dielectrics	entation, exemplification, problem exercise, case study,	, p
о.	Breakdown of dielectrics. Dielectric materials used in electronics.		Jse of .ppt presentation, projector, blackboard
0		n inc	tat
9.	Semiconductor materials – definitions, classifications and general aspects	sat ach atio	sen
10	Intrinsic semiconductors	Pres heuristic conversation, presentation, teaching formative evaluation	lee
	. Extrinsic semiconductors	on, ava	ot p
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	. PN junction. Some semiconductors used in electronics.	ent ativ	of
	. Conductors	an se s	Se
	. Magnetic materials. Preparation for the final exam.	<u> </u>	
Bibliog			
1.	· · · 3 · · · · · · · · · · · · · · · ·		
2.	Angus Rockett - The Materials Science of Semiconductors,		
3.	William D Callister, Jr David G Rethwish - Materials Science	e and Engineering An	
3.	William D Callister, Jr David G Rethwish - Materials Science Introduction, 2018.	e and Engineering An	
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	Introduction, 2018.	design 4 th ed., 2010.	
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9. Bridging course contents with the expectations of the representatives of the community, professional associations and employers in the field





The discipline content and the acquired skills are in agreement with the expectations of the professional organizations and the employers in the field, where the students carry out the internship stages and/or occupy a job (in the field of *electronics and telecommunications engineering*), and the expectations of the national organization for quality assurance (ARACIS).

10. Evaluation

Activity type	10.1 Assessment criteria	10.2 Assessment	10.3 Weight in
, iouilly type		methods	the final grade
10.4 Course	and practical skills	Summative evaluation written exam (theory and problems)	80%
10.5 Seminar/ Laboratory	The level of acquired knowledge and abilities	 Continuous formative evaluation practical lab test 	20%

10.6 Minimum standard of performance

Quality level:

Minimal knowledge:

- ✓ Knowledge of the main properties of conductive, semiconductor, insulating and magnetic materials.
- \checkmark Knowledge of the main materials used in electronics.

Minimal competences:

- \checkmark To be able to list the main properties of materials used in electronics.
- \checkmark To be able to specify the main advantages and disadvantages of the materials used in electronics.

Quantitative level:

- ✓ To perform all laboratory works
- ✓ The exam and laboratory marks must be at least 5
- ✓ The final mark for the subject is calculated with the relation: 0.8 * Exam mark + 0.2 * Lab mark

Date of filling in:	Responsible	Title Surname NAME	Signature
20.06.2023	Course	Lect. Prof. Alexandra Fodor, PhD Eng.	
	Applications	Lect. Prof. Ionuţ Ciocan, PhD Eng.	



Facultatea de Electronică, Telecomunicatții și Tehnologia Informației



Date of approval in the Department of

30.06.2023

Date of approval in the Council of Faculty of Electronics, Telecommunications and Information Technology Prof. Dorin PETREUŞ, PhD eng

Head of Department

Dean Prof.Ovidiu Aurel POP, PhD eng

12.07.2023